

2MBI200VA-060-50

IGBT Modules

IGBT MODULE (V series) 600V / 200A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items		Symbols Conditions			Maximum ratings	Units	
Collector-Emitter voltage		Vces		,	600	V	
Gate-Emitter voltage		V _{GES}			±20	V	
Collector current		Ic	Continuous	Tc=100°C	200		
		I _{C pulse}	1ms		400	٨	
		-Ic				Α	
		-I _{C pulse}	1ms	,	400		
Collector power dissipation		Pc	1 device		650		
Junction temperature		T _j			175		
Operating junction temperature (under switching conditions)		T _{jop}			150	°C	
Case temperature		Tc			125	C	
Storage temperature		T _{stg}		,	-40 ~ 125		
Isolation voltage	between terminal and copper base (*1)	Viso	AC: 1min.		2500	VAC	
Screw torque	Mounting (*2)	-			5.0	N m	
	Terminals (*3)	-			5.0	IN III	

Note *1: All terminals should be connected together when isolation test will be done.

Note *2: Recommendable Value : 3.0-5.0 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T_i= 25°C unless otherwise specified)

lama	Cumbala	Conditions		Characteristics			l lusita
Items	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 600V		-	-	1.0	mA
Gate-Emitter leakage current	-Emitter leakage current I_{GES} $V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	200	nA	
Gate-Emitter threshold voltage	V _{GE (th)}	$V_{CE} = 20V, I_{C} = 200mA$		6.2	6.7	7.2	V
	V _{CE (sat)}	V _{GE} = 15V I _C = 200A	T _j =25°C	-	1.80	2.25	V
	(terminal)		T _j =125°C	-	2.10	-	
Collector-Emitter saturation voltage			T _j =150°C		2.30		
Conector-Emitter Saturation Voltage	V _{CE (sat)} (chip)	V _{GE} = 15V I _C = 200A	T _j =25°C	-	1.60	2.05	
			T _j =125°C	-	1.90	-	
			T _j =150°C		2.10		
Internal gate resistance	R _G (int)	-			4	-	Ω
Input capacitance	Cies	$V_{CE} = 10V, V_{GE} = 0V, f = 1W$	-	12.8	-	nF	
	ton	$V_{\text{CC}} = 300V$		-	650	-	nsec
Turn-on time	tr			-	300	-	
	t r (i)			-	100	-	
Turn-off time	toff			-	600	-	
Turn-on time	t _f			-	40	-	
	VF	V _{GE} = 0V I _F = 200A	T _j =25°C	-	1.70	2.15	V
	(terminal)		T _j =125°C	-	1.60	-	
Forward on voltage	(terrillial)	IF - 200A	T _j =150°C		1.57		
rorward on voltage	VF	V _{GE} = 0V I _F = 200A	T _j =25°C	-	1.60	2.05	
			T _j =125°C	-	1.50	-	
	(chip)	IF - 200A	T _j =150°C		1.47		
everse recovery time t_{rr} $I_F = 200A$		-	200	-	nsec		

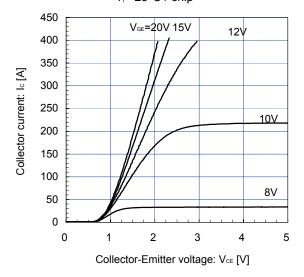
Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items		Conditions	min.	typ.	max.	Units
Thermal resistance (Aderrica)	Ь	IGBT	-	-	0.23	°C/W
Thermal resistance (1device)	R _{th(j-c)}	FWD	-	-	0.41	
Contact thermal resistance (1device) (*4)	R _{th(c-f)}	with Thermal Compound	-	0.050	-	

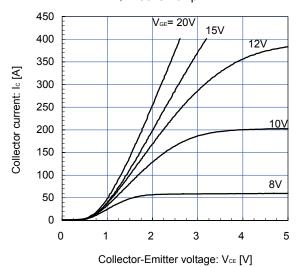
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

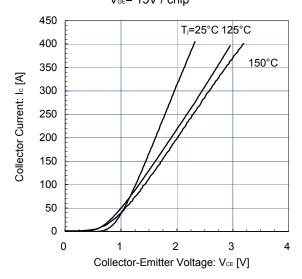
Collector current vs. Collector-Emitter voltage (typ.) $T_j = 25^{\circ}C$ / chip



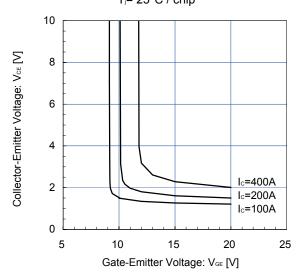
Collector current vs. Collector-Emitter voltage (typ.) T₌ 150°C / chip



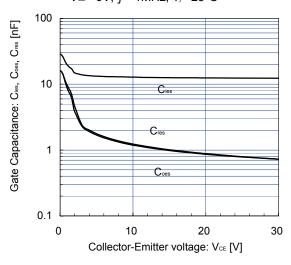
Collector current vs. Collector-Emitter voltage (typ.) V_{GE} = 15V / chip



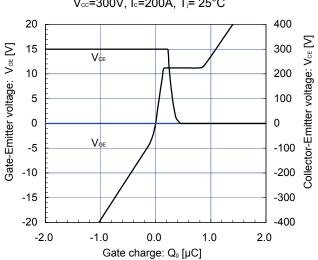
Collector-Emitter voltage vs. Gate-Emitter voltage T_j= 25°C / chip

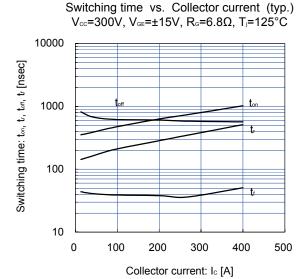


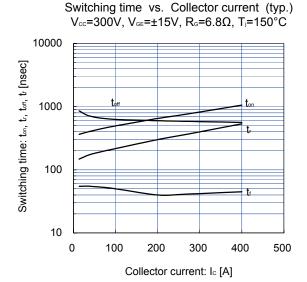
Gate Capacitance vs. Collector-Emitter Voltage V_{GE} = 0V, f= 1MHz, T_{J} = 25°C

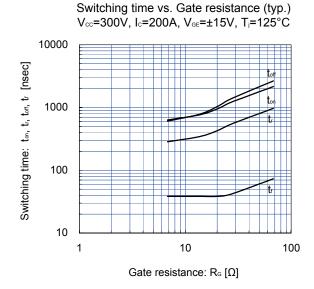


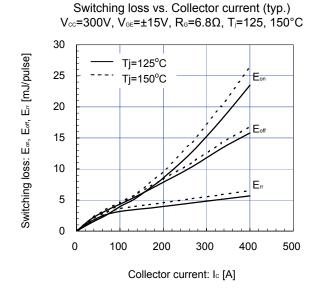
Dynamic Gate Charge (typ.) V_{cc}=300V, I_c=200A, T_i= 25°C

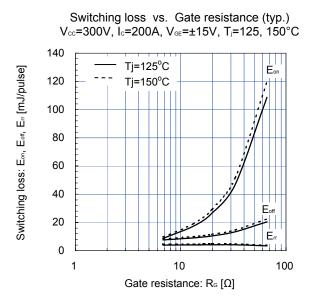


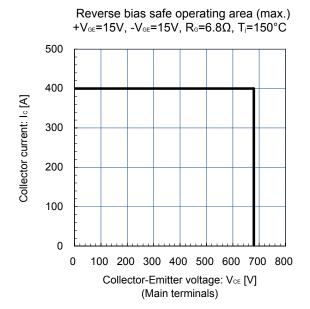




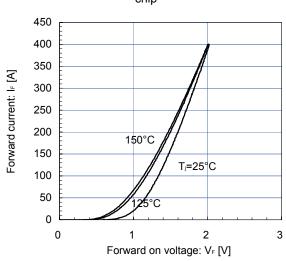




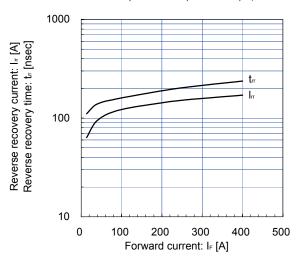




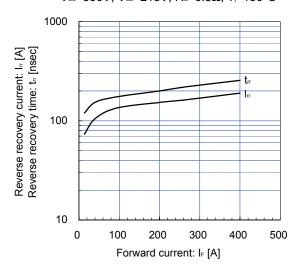
Forward Current vs. Forward Voltage (typ.) chip



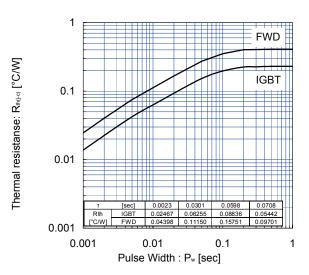
Reverse Recovery Characteristics (typ.) V_{CC} =300V, V_{GE} =±15V, R_{G} =6.8 Ω , T_{J} =125°C



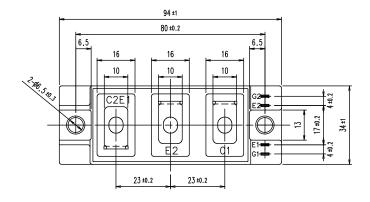
Reverse Recovery Characteristics (typ.) V_{CC} =300V, V_{GE} =±15V, R_{G} =6.8 Ω , T_{J} =150°C

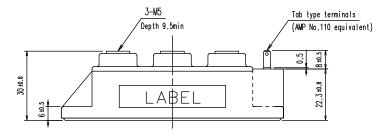


Transient Thermal Resistance (max.)

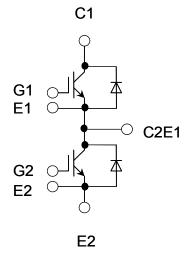


■ Outline Drawings, mm





■ Equivalent Circuit Schematic



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